

Simple Phase Control Circuit

Description

Integrated circuit, TEA1007, is designed as a general phase control circuit in bipolar technology. It has an internal supply voltage limitation. With typical 150 mA ignition pulse, it is possible to determine the phase-shift

of the ignition point by comparing the mains sync. ramp voltage with a preset required value. It generates a single ignition pulse per half wave; therefore, it is suitable for capacitive and inductive loads in low cost applications.



Figure 1. Block diagram with typical circuitry

General Description

The phase-shift of the ignition point is determined in the usual manner by comparison between a mains synchronized ramp voltage and a predetermined required value. The capacitor $C_{\phi/t}$ between Pin 7 and the common reference point Pin 8 is discharged at the zero transition of the mains voltage via the V_0 detector, gate G_2 and switch S_2 . After the end of the zero transition pulse, $C_{\phi/t}$ is charged from the constant current source I_{ϕ} , whose value is adjusted externally with R_{ϕ} at Pin 3 due to the unavoidable tolerance of $C_{\phi/t}$ (Phase 1).

When the potential at Pin 7 reaches the nominal value predetermined at Pin 6, the thyristor Th₁, which also functions as a comparator, ignites and sets the following clock flip-flop. The output of the clock flip-flop releases the output amplifier, connects a second constant current source to the capacitor $C_{\phi/t}$, and switches the reference voltage switch S₁ to an internally generated threshold voltage V_{Ref1} via an RS flip-flop and the OR gate G₁.

The capacitor $C_{\phi/t}$ is charged in this second phase by $I_{\phi} + I_{tp}$ until it reaches the internal reference voltage $V_{Ref.}$ The length of this Phase 2 corresponds to the width of the output pulse tp. When the capacitor voltage reaches the value V_{Ref} , thyristor Th₁ ignites again and resets the clock flip-flop to its initial state. The output pulse is thus terminated and the constant source I_{tp} is switched off. However, the RS flip-flop holds the switch S_1 so that the internal reference voltage remains connected to Th₁. As V_{Ref} is greater than the maximum permissible control voltage at Pin 6, this prevents more than one ignition pulse from being generated in each half-cycle of the mains voltage. This is particularly important because the energy contents of the output pulse is of the same order as the internal requirements of the circuit (for) each half-wave.

In the following zero transition of the mains voltage, the zero transition detector (Input Pin 5) resets the RS flip-flop, discharges $C_{\phi/t}$ again via S_2 , and also insures that the clock flip-flop is in the reset condition. A further part of the basic function is the current detector with its input at Pin 4. When controlling inductive loads, the load current lags behind the mains voltage which means that the circuit could generate an ignition pulse during the period in which current is still flowing with a polarity opposite to that of the mains voltage if the current were not taken into account (see figure 2).

This, in turn, would lead, to so-called "gaps" in the load current as the next ignition pulse is generated in the subsequent half-cycle.



Figure 2. Functional diagram for inductive load of α_{max}



Figure 3. Triac voltages + currents at resistive load

- V_o = Zero cross voltage
- $I_O = Zero cross current$
- $V_M = Mains voltage$
- $I_L = Load current$
- I_G = Gate current
- V_{HI} = Triac voltage at anode HI



In indication as to whether load current is flowing or not is provided by the triac itself. When the triac is ignited, the voltage at electrode H₁ drops from the instantaneous value of the mains voltage to approximately 1.5 V, the value of the forward voltage of the triac. When the load current drops below the hold current of the triac towards the end of the half-cycle, V_{H1} again returns to the instantaneous value of the mains voltage. The current detector with its input at Pin 4 now controls this triac voltage and blocks the pulse generator via G₁ and S₁ by increasing the reference voltage as long as the triac is conducting. As, in the case of a resistive load, the triac may be extinguished shortly before the zero transition of the mains voltage when the load current drops below the hold current – the RS flip-flop must prevent any possible second ignition pulse from being generated.



Figure 4. Functional diagram for resistive load and α_{min}

Additional Function

An internal supply voltage control circuit insures that output pulses can be generated only when the supply voltage required for operation of all-logic functions is available.

Series resistance R_1 can be calculated approx. as follows:

$$R_{1 \text{ max}} = 0.85 \frac{V_{M \text{ min}} - V_{S \text{ max}}}{2 \times I_{tot}}$$

$$I_{tot} = I_S + I_P + I_x \text{ whereas}$$

 $I_{tot} = Total current consumption$

- I_{S} = Current requirement of the IC
- I_P = Average current requirement of the triggering pulses
- I_x = Current requirement of other peripheral components

Determination of Gate Series Resistance, Firing Current and Pulse Width

Firing current requirement depends upon the triac used which can be regulated with series resistance as given below:

$$\begin{split} \mathbf{R}_{\mathrm{G \,max}} &\approx \frac{12.5 \ \mathrm{V} - \mathrm{V}_{\mathrm{G \,max}}}{\mathrm{I}_{\mathrm{G \,max}}} - 110 \ \Omega \\ \mathbf{I}_{\mathrm{P}} &= \frac{\mathrm{I}_{\mathrm{G}}}{\mathrm{T}} \times \mathrm{t}_{\mathrm{p}} \\ \mathrm{t}_{\mathrm{P}} &\approx \frac{8 \ \mu \mathrm{s}}{\mathrm{nF}} \times \mathrm{C}_{\mathrm{\phi}} \end{split}$$

whereas:

VG =Triac's gate voltage

 I_{G} =Triac's gate current

=Gate current requirement - average IΡ

Т =Period duration of mains frequency

=(firing) pulse width $t_p \\ C_\phi$

=Ramp capacitor

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Absolute Maximum Ratings

Reference point Pin 8

Parameters			Symbol	Value	Unit
Current consumption		Pin 1	$-I_S$	30 <	mA
t<10 ms			-i _s	60	
Sync. currents:		Pin 4	I _{syncI}	10	mA
		Pin 5	I _{syncV}	10	\sim
t-	<10 ms	Pin 4	$\pm i_{sync.I}$	60	2
		Pin 5	$\pm i_{sync.V}$	60	
Input current		Pin 3	$-I_{I}$	5	mA
Input voltages:		Pin 6	$-V_{I}$	≦Vs ~~~~	V
		Pin 2	VI	$-V_{S} \leq V_{I} \leq 2$	
Power dissipation					
$T_{amb} = 45^{\circ}C$			P _{tot}	400	mW
$T_{amb} = 85^{\circ}C$				225	
Junction temperature			Tj	125	°C
Ambient temperature range			T _{amb}	0 to 80	°C
Storage temperature range			T _{stg}	-40 to +125	°C

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	DIP8 SO8 (P.C.) SO8 (ceramic)	RthJA	200 220 140	K/W
		$\mathcal{A}(\mathcal{D})$		•

Electrical Characteristics

Reference point Pin 8, unless otherwise specified

Parameters	Test Conditions / P	Pin	Symbol	Min	Туре	Max	Unit
Mains supply	Pi	in 1	$-V_S$	13.5		17	V
Current consumption	$(\langle \rangle)$		IS			2.5	mA
Sync. currents	Pi	in 4	I _{syncI.}		0.35		mA
	Pi Pi	in 5	I _{syncV}		0.65		
Output pulse current	$V_{\rm S} = (13.5)^{\rm V}$		•				mA
	$R_G = 0, V_G = 1.2 V P_I$	in 2		IO	90	180	
Output pulse width	$C_{0/t} = 3.3 \text{ nF}$ Pi	in 2	tp	8		30	μs
	$C_{0/t} \ge 6.8 \text{ nF}$		tp	15		64	
Charge current	"Phase 1" Pi	'in 7	Ι _φ	1		20	μA
	$C_{\phi/t} = 3.3 \text{ nF}$				2		
	$\mathcal{C}_{\phi/t} = 6.8 \text{ nF}$				4.3		
	"Phase 2" Pi	in 7	It		1.3		mA
Drive current	P	'in 6	Ii			0.5	μA
Balance between two half	$V_6 = constant$						
cycles			Δφ			±3	0



Applications



Figure 6. Two-phase time-switch, 230 V \sim

TEA1007

The timing switch using the TEA 1007 permits two-phase operation of loads with conduction angle ö adjustable as required (see figure 6).

 $\begin{array}{ll} \mbox{Phase 1:} & & \mbox{adjustable with } R_{21} \\ \mbox{Period } t = 5 \mbox{ to } 320 \mbox{ sec } & \mbox{adjustable with } R_{22} \\ \mbox{Phase 2:} & & \mbox{adjustable with } R_{20} \\ \mbox{Period } t = \mbox{optional, or up to the pressed time of switch } S \end{array}$

Phase 1 begins as soon as the mains voltage is applied. The maximum angle of conduction φ_{max} can be adjusted by means of R₂₁. The timing circuit comprises T₁, T₂, Z₁, C_3 and R_{22} . As the voltage to which C_3 is charged increases, the current through Z_1 decreases. When the potential at the emitter of T_2 has climbed so high that the current through Z_1 becomes zero, T_1 can no longer conduct. The potential on R_{21} therefore drops. The conduction angle φ decreases to the value φ_{min} , adjustable by means of R_{20} (Phase 2).

The transition from φ_{max} to φ_{min} takes place continuously following the adjustment of R_{22} and takes ca. 2 to 20 secs. The time constant of Phase 1, which is also determined by R_{22} , begins with the release of key S. If S is pressed again before the end of the time constant, a period equal to the complete time-constant is added to the time already run.

The circuit is powered direct from mains via D_1 and R_1 in every negative half-cycle. C_1 smooths the operating voltage which settles at a level of ca. 15.5 V.





Dimensions in mm

Package: DIP8



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